

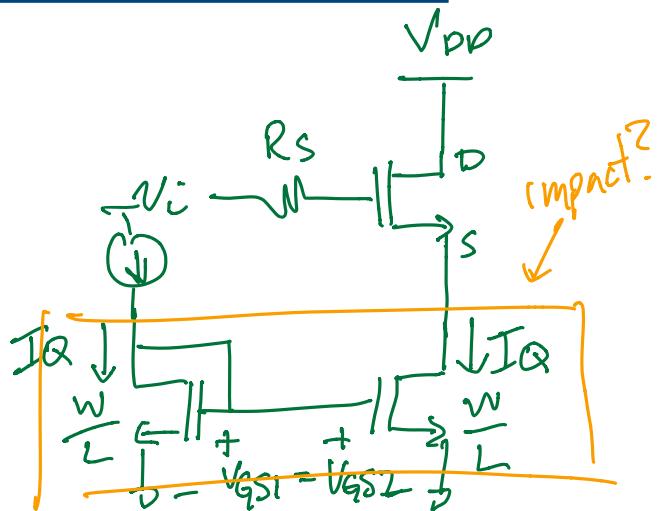
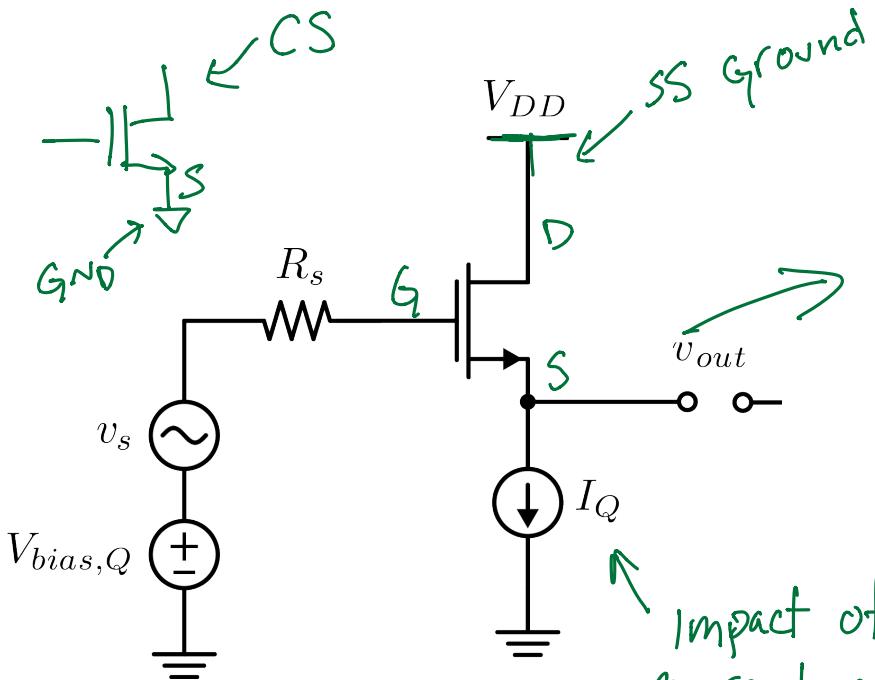
Frequency Response

**Prof. Ali M. Niknejad
Prof. Rikky Muller**

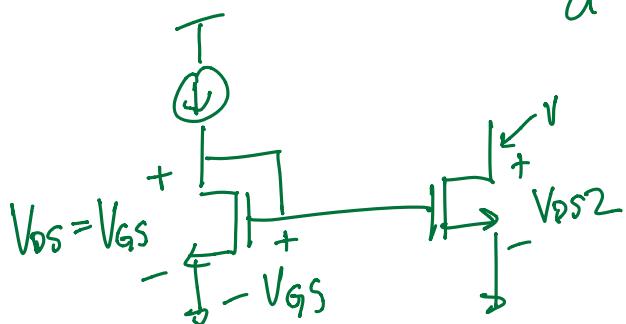
Announcements

- HW9 due on Friday
- LAB 5 EXTENDED

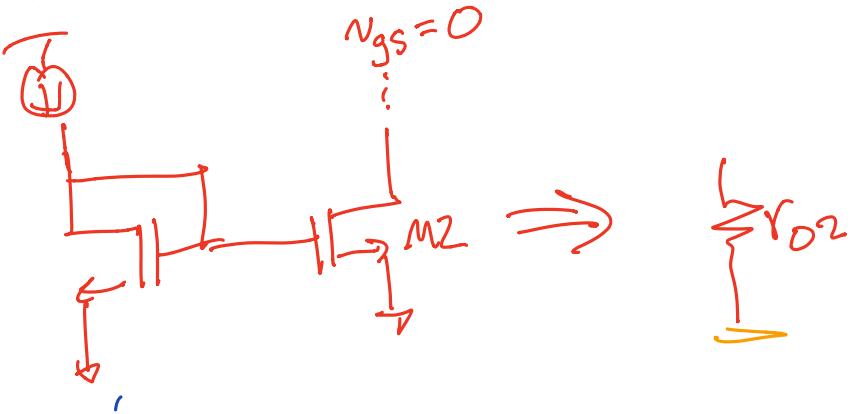
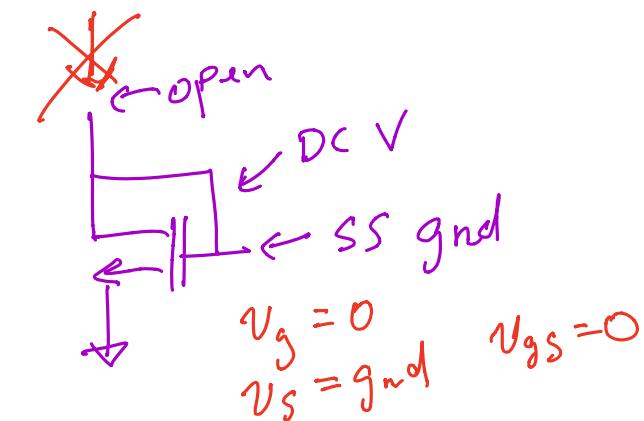
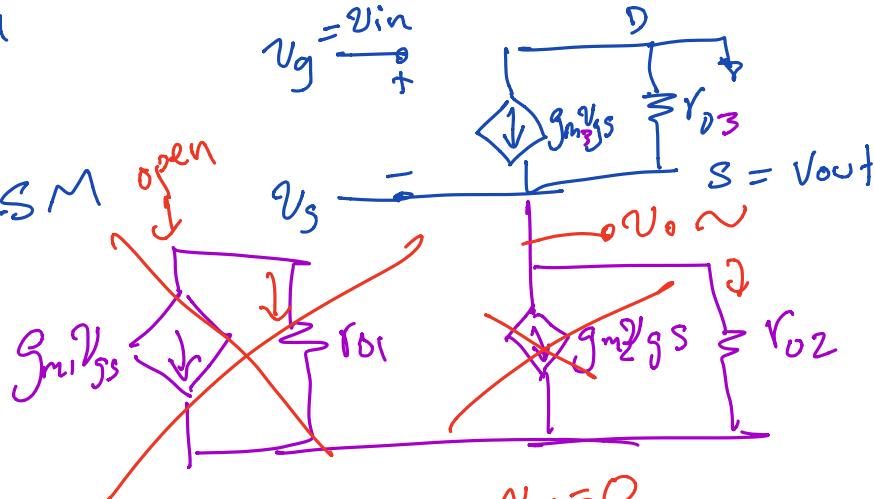
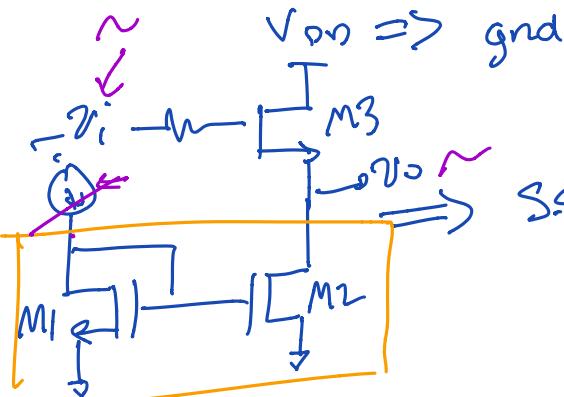
Review: CD with Current Mirror



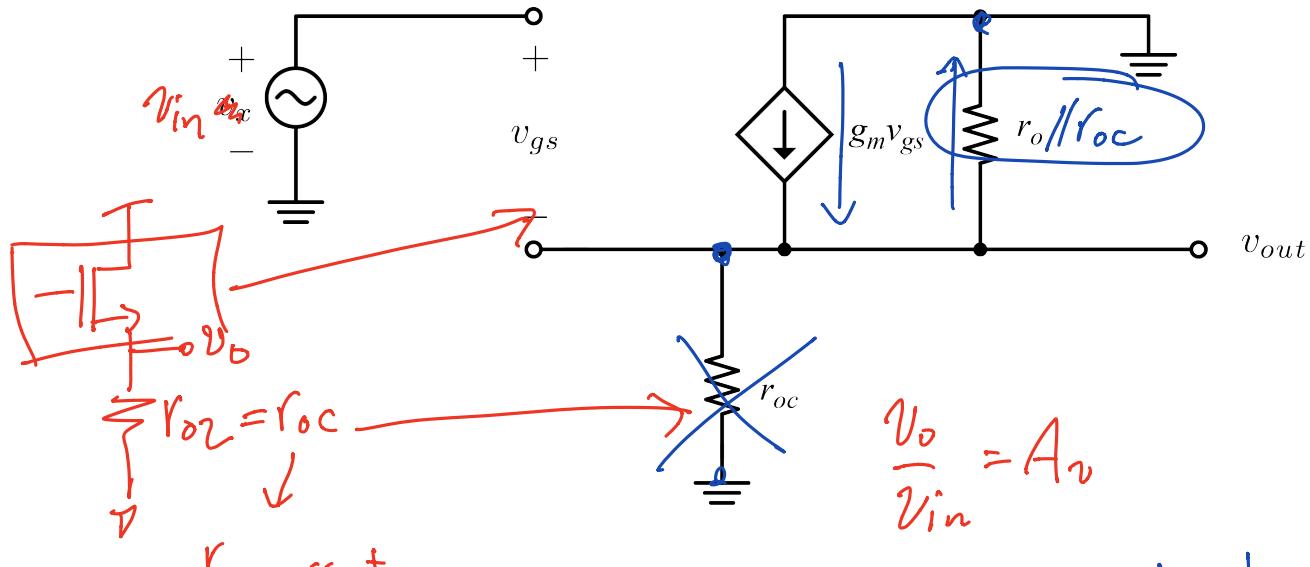
$$I_{DS} = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_T)^2 (1 + \lambda V_{DS})$$



Review: CD with Current Mirror



Review: CD with Current Mirror



$$\frac{v_o}{r_o // r_{oc}} = g_m v_{gs} = g_m (v_{in} - v_{out})$$

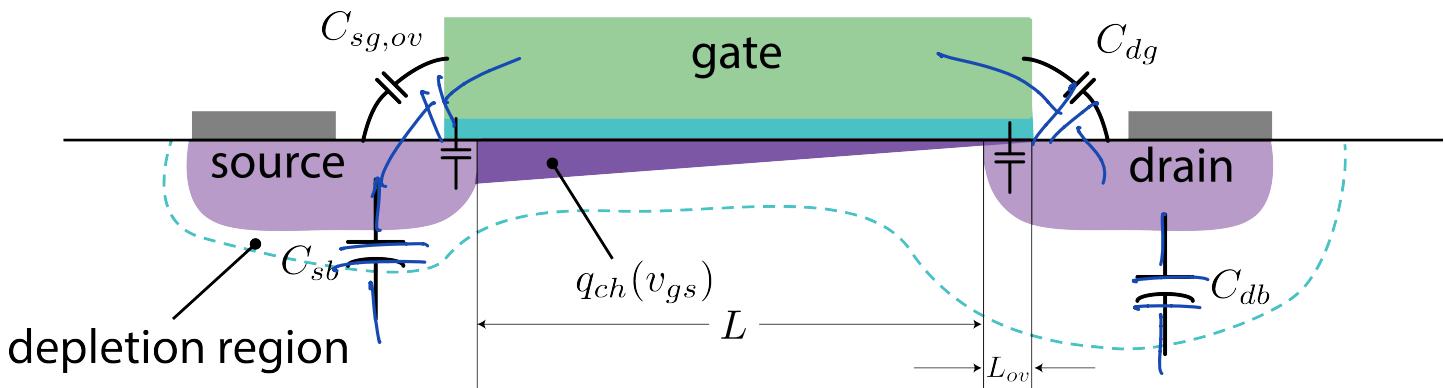
$$v_{out} \left(\frac{1}{r_o // r_{oc}} + g_m \right) = g_m v_{in}$$

v_{out} $g_m (r_o // r_{oc})$

$$\frac{v_{out}}{v_{in}} = \frac{g_m}{g_m + \frac{1}{r_o // r_{oc}}}$$

$$\overline{V_{in}} = \frac{g_m(V_{th} + V_{GS})}{g_m(R_{on} || R_{oc}) + 1}$$

Capacitors in MOS Device



large cap

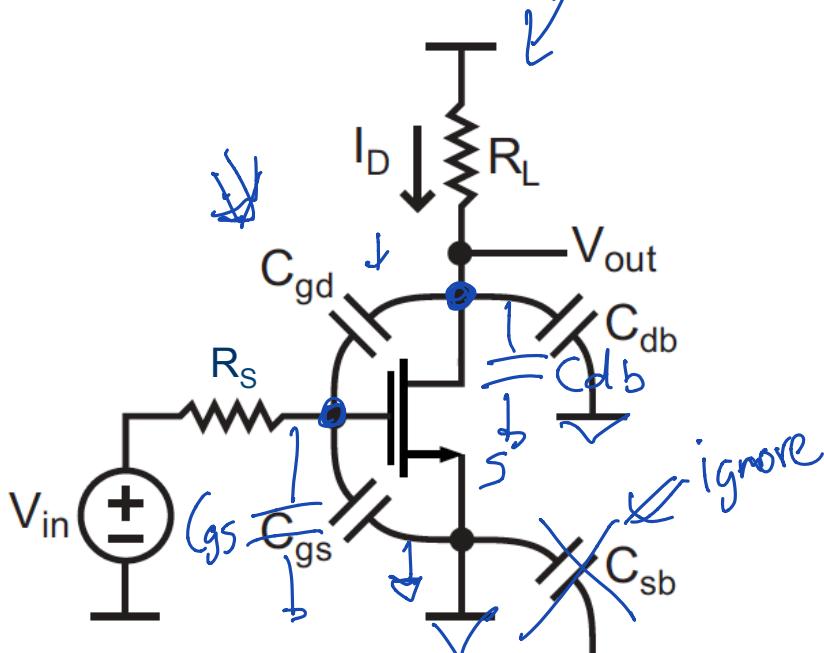
$$\Rightarrow C_{gs} = (2/3)WL\underline{C_{ox}} + C_{ov} \leftarrow \text{probably largest}$$

$\cancel{C_{gd} = C_{ov}}$ small but problematic

$$C_{sb} = C_{jsb}(\text{area} + \text{perimeter}) \text{junction}$$

$$C_{db} = C_{jdb}(\text{area} + \text{perimeter}) \text{junction}$$

Common-Source Voltage Amplifier



Small-signal model:

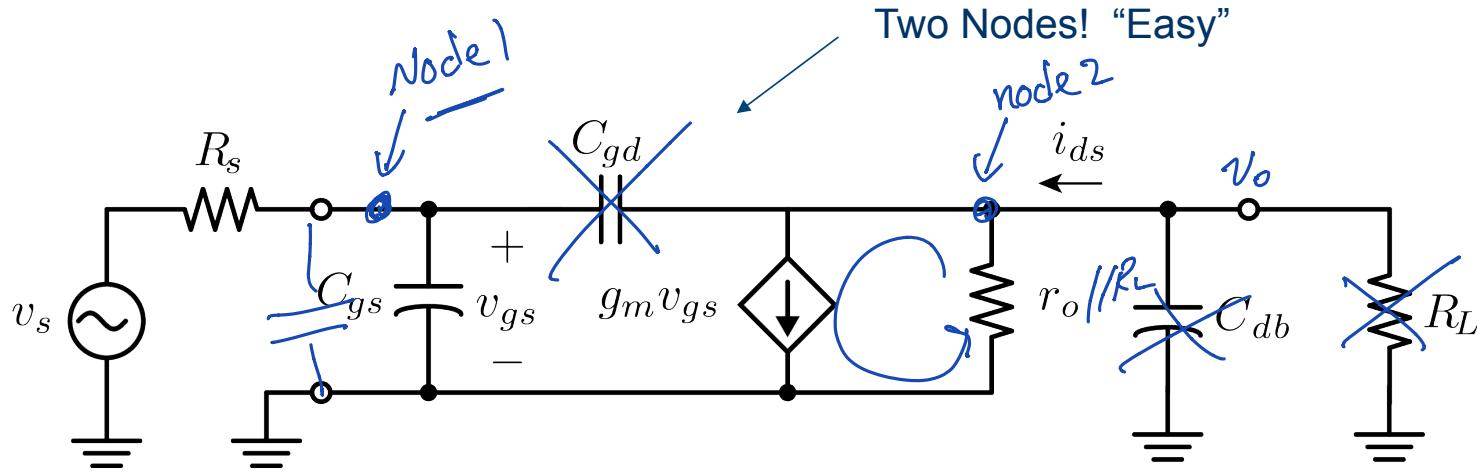
C_{sb} is connected to gnd on both sides, therefore can be ignored

Can solve problem directly by nodal analysis or using 2-port models of transistor

OK if circuit is “small”
(1-2 nodes)

We can find the complete transfer function of the circuit, but in many cases it's good enough to get an estimate of the -3dB bandwidth

CS Voltage Amp Small-Signal Model



For now we will ignore C_{db} to simplify the math

$$g_m v_{gs} = -\frac{v_o}{r_o \parallel R_L}$$

$$g_m v_{in} = -\frac{v_o}{r_o \parallel R_L} \quad \frac{v_o}{v_{in} - v_i} = -\frac{g_m (v_i \parallel R_L)}{R_L}$$

Frequency Response

KCL at input and output nodes; analysis is made complicated

$$\frac{V_{out}}{V_{in}} = \frac{-g_m [r_o \parallel R_L] (1 - j\omega / \omega_z)}{(1 + j\omega / \omega_{p1})(1 + j\omega / \omega_{p2})}$$

↑ DC gain

Zero

↑ Two Poles

Low-frequency gain:

$$\frac{V_{out}}{V_{in}} = \frac{-g_m [r_o \parallel R_L] (1 - j0)}{(1 + j0)(1 + j0)} \rightarrow -g_m [r_o \parallel R_L]$$



Zero: $\omega_z = \frac{g_m}{C_{gs} + C_{gd}}$

Calculating the Poles

dominant pole

ω_{p1}

$$\omega_{p1} \approx \frac{1}{R_s \left\{ C_{gs} + (1 + g_m R'_s) C_{gd} \right\} + R'_s C_{gd}}$$

same denominator

ω_{p2}

$$\omega_{p2} \approx \frac{R'_s / R_s}{R_s \left\{ C_{gs} + (1 + g_m R'_s) C_{gd} \right\} + R'_s C_{gd}}$$

R'_s / R_s

DC gain

-3dB

BW

ω_{p1}

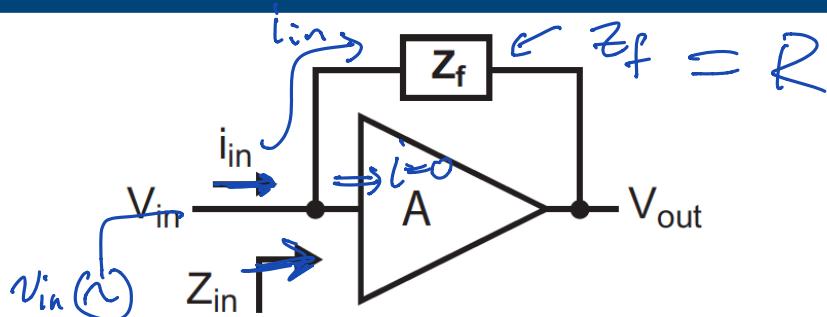
Usually $\gg 1$

much higher frequency

Results of complete analysis: not exact and little insight

These poles are calculated after doing some algebraic manipulations on the circuit. It's hard to get any intuition from the above expressions. There must be an easier way!

Method: The Miller Effect



- Derive input impedance (assume gain of amplifier = A):

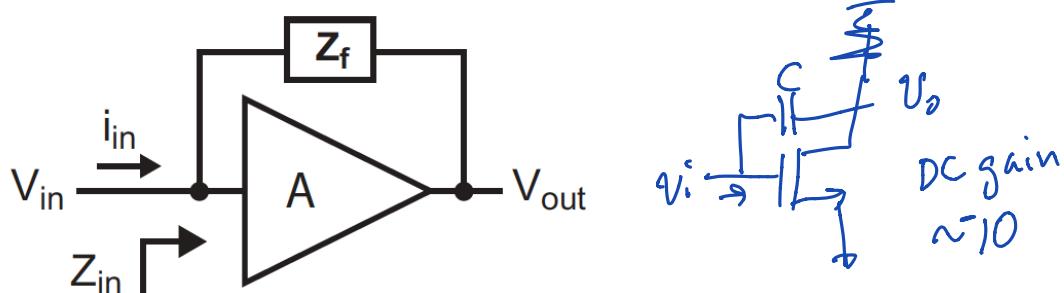
$$i_{in} = \frac{V_{in} - V_{out}}{Z_f} \quad V_{out} = A V_{in}$$

$$Z_{in} = \frac{V_{in}}{i_{in}}$$

$$i_{in} = \frac{V_{in} - A V_{in}}{Z_f} = V_{in} \frac{1 - A}{Z_f}$$

$$\frac{V_{in}}{i_{in}} = \frac{Z_f}{1 - A}$$

The Miller Effect



- Derive input impedance (assume gain of amplifier = A):

$$Z_{in} = \frac{V_{in}}{i_{in}} = \frac{V_{in}}{(V_{in} - V_{out})/Z_f} = \frac{V_{in}Z_f}{V_{in} - AV_{in}} = \frac{Z_f}{1 - A} = \frac{1}{sC}$$

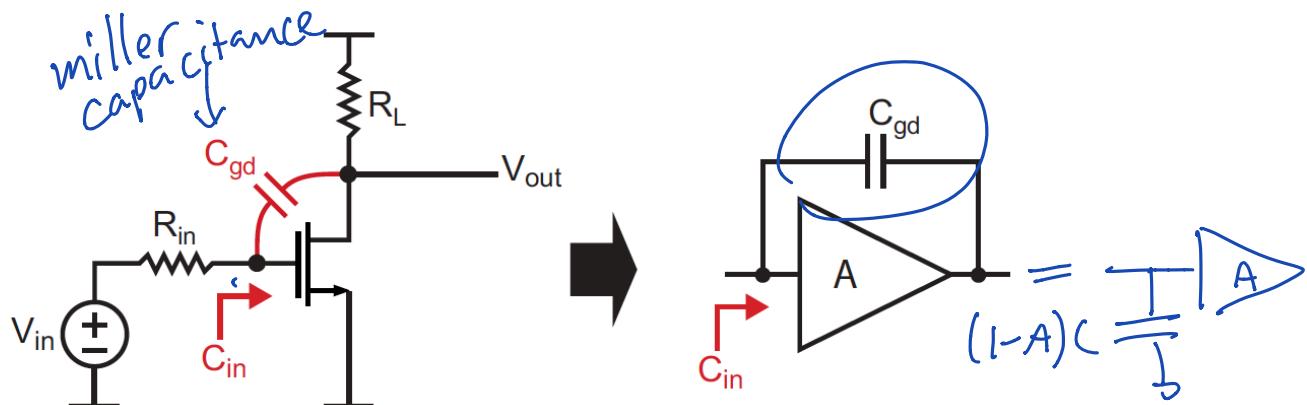
- Consider the case where Z_f is a capacitor

$$Z_f = \frac{1}{sC} \Rightarrow Z_{in} = \frac{1}{s(1-A)C} \leftarrow \text{very large capacitance}$$

- For negative A , input impedance sees increased cap value
- For $A = 1$, input impedance sees no influence from cap
- For $A > 1$, input impedance sees negative capacitance!

$$Z_{in} = \frac{1}{s(1-A)C}$$

Using The Miller Effect



- Notice that C_{gd} is in the feedback path of the common source amplifier

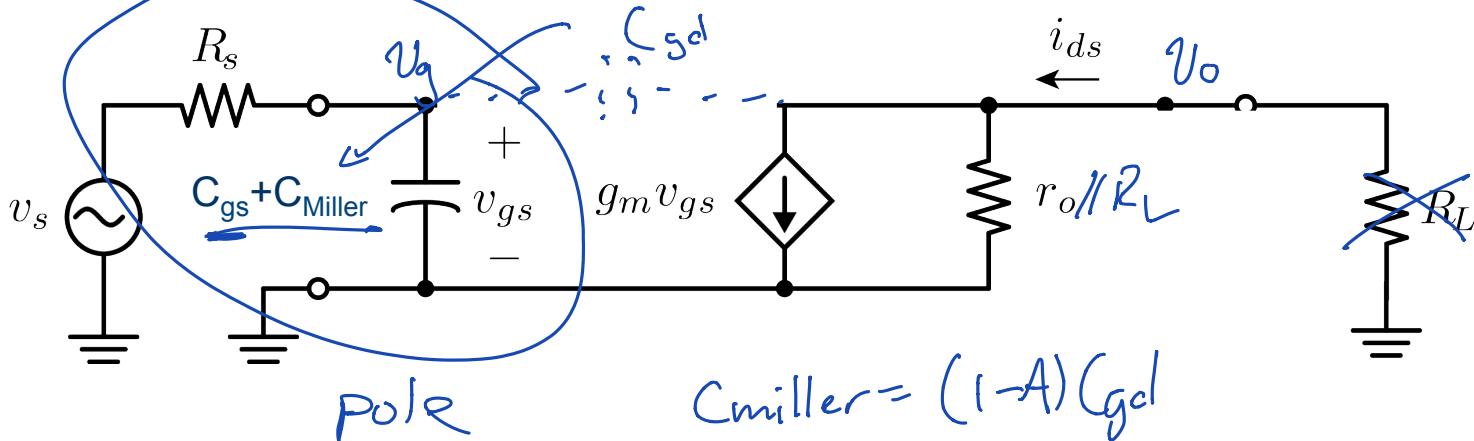
— Recall Miller effect calculation: $\underline{C_{in} = (1 - A)C_{gd}}$

Effective input capacitance:

$$C_{in} = \frac{1}{j\omega C_{Miller}} = \left(\frac{1}{1 - A_{v,Cgd}} \right) \left(\frac{1}{j\omega C_{gd}} \right) = \frac{1}{j\omega [(1 - A_{v,Cgd}) C_{gd}]}$$

CS Voltage Amp Small-Signal Model

Modified Small-Signal Model with Miller Effect:



We can approximate the first pole by using Miller capacitance
This gives us a good approximation of the -3dB bandwidth ω_p approx.

$$\frac{v_g}{v_s} = \frac{\frac{1}{(C_{gs} + C_{Miller})s}}{\frac{1}{(C_{gs} + C_{Miller})s} + R_s} = \frac{1}{1 + R_s(C_{gs} + C_{Miller})s}$$

$$\frac{v_o}{v_g} = -g_m(r_o \parallel R_L)$$

$$\frac{v_o}{v_s} = \frac{-g_m(r_o \parallel R_L)}{(1 + R_s(C_{gs} + C_{Miller})s)^2} s \leftarrow \text{pole! } \omega_p = \frac{1}{R_s(C_{gs} + C_{Miller})}$$

Comparison with “Exact Analysis”

Miller result (calculate RC time constant of input pole):

$$\omega_{p1}^{-1} = R_S \left[C_{gs} + \frac{(1 + g_m R'_\text{out}) C_{gd}}{(-A)} \right]$$

Miller

Exact result:

$$\omega_{p1}^{-1} = R_S \left[C_{gs} + \frac{(1 + g_m R'_\text{out}) C_{gd}}{\text{large}} \right] + R'_\text{out} C_{gd}$$

As a result of the Miller effect there is a fundamental gain-bandwidth tradeoff

$$\begin{aligned} \text{DC gain} &= -g_m (r_o || R_L) = -g_m R'_\text{out} \\ \omega_{p1}^{-1} &\approx R_S (C_{gs} + R_S (1 + g_m R'_\text{out}) C_{gd}) \end{aligned}$$

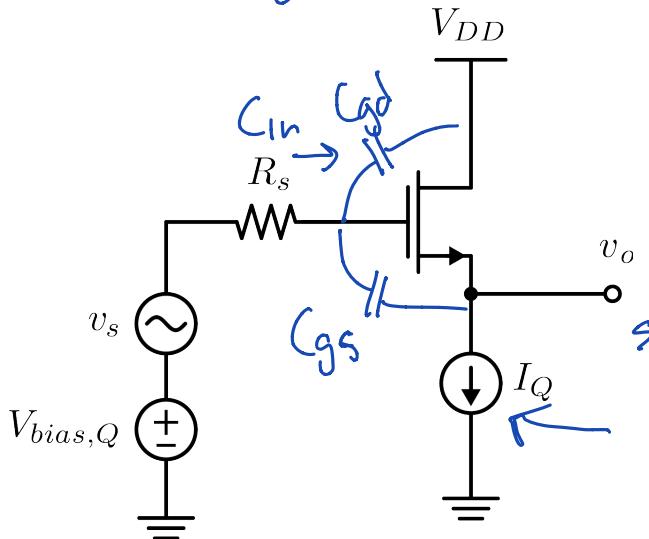
tradeoff

if we multiply gain \times BW \sim constant

Common Drain Amplifier

"Source follower"

DC result is different
gain $\sim +1$

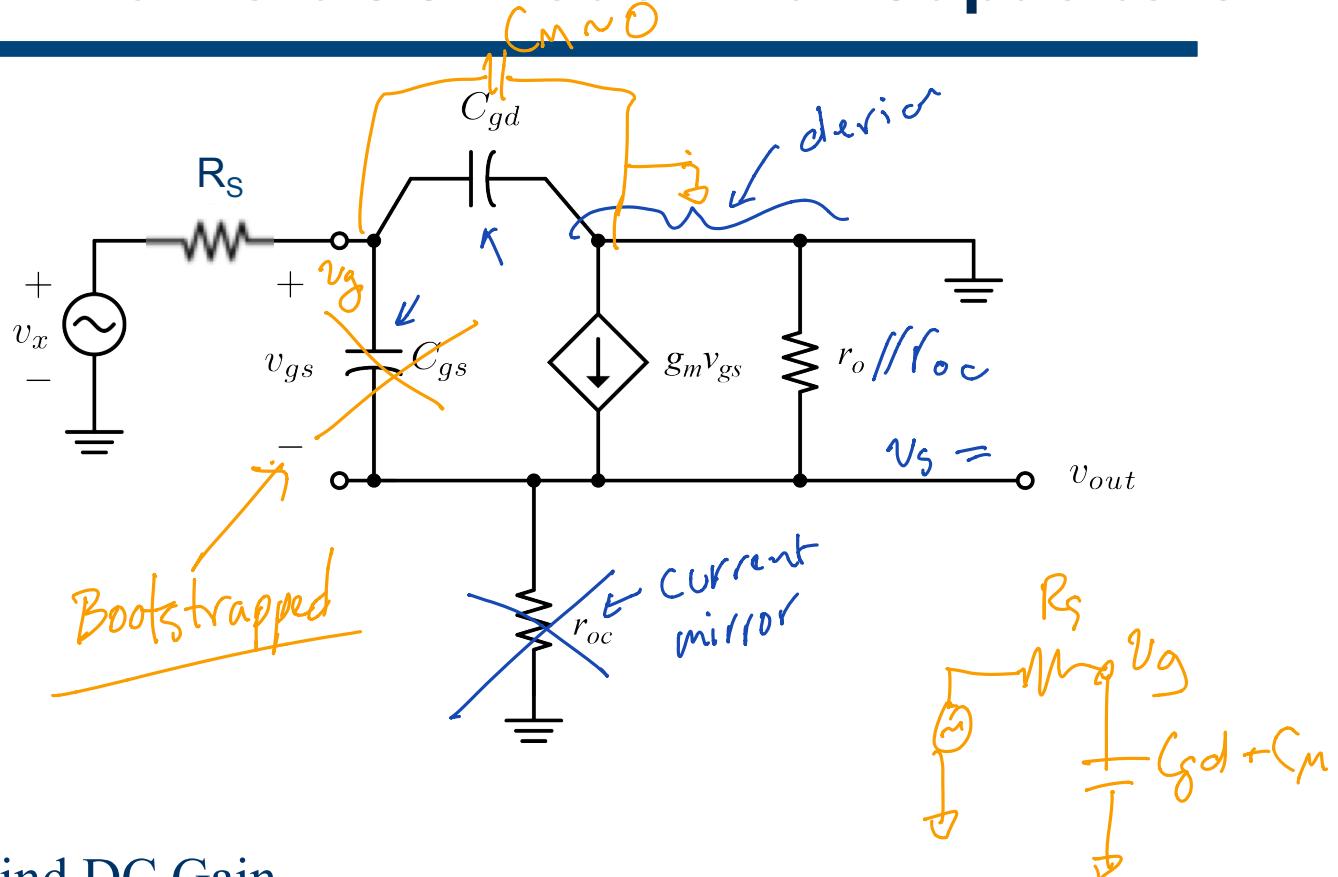


Calculate Bandwidth of the Common Drain (Source-Follower)

Procedure:

1. Replace current source with MOSFET-based current mirror
2. Draw small-signal model with capacitors (for simplicity, we will focus on C_{gd} and C_{gs})
3. Find the ~~DC~~ small-signal gain ~ 1
4. Use the Miller effect to calculate the input capacitance
5. Calculate the dominant pole

Two-Port CC Model with Capacitors



- Find DC Gain
- Find Miller capacitor for C_{gs} -- note that the gate-source capacitor is between the input and output!

Voltage Gain Across C_{gs}

Write KCL at output node:

$$\frac{v_{out}}{r_o \parallel r_{oc}} = g_m v_{gs} = g_m (v_{in} - v_{out})$$

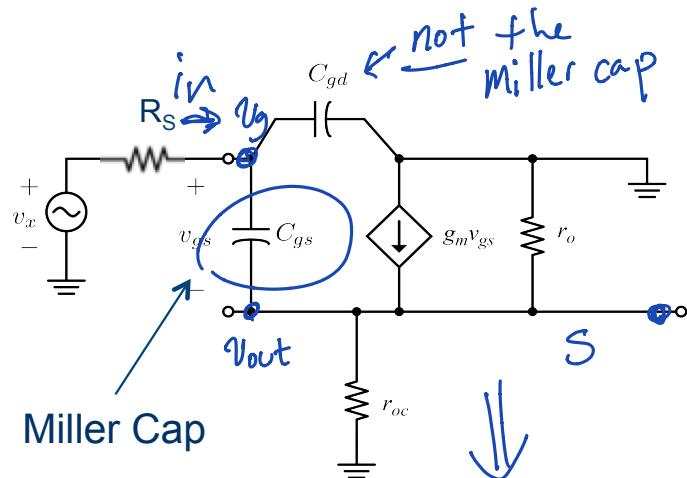
$$v_{out} \left(\frac{1}{r_o \parallel r_{oc}} + g_m \right) = g_m v_{in}$$

$$\frac{v_{out}}{v_{in}} = \frac{g_m}{\left(\frac{1}{r_o \parallel r_{oc}} + g_m \right)} = \frac{g_m (r_o \parallel r_{oc})}{1 + g_m (r_o \parallel r_{oc})} = A_{vCgs}$$

Compute Miller Effect Capacitance

Now use the Miller Effect to compute C_{in} :

Remember that C_{gs} is the capacitor from the input to the output



$$C_{in} = C_{gd} + C_M$$

$$C_{in} = C_{gd} + (1 - A_v C_{gs}) C_{gs}$$

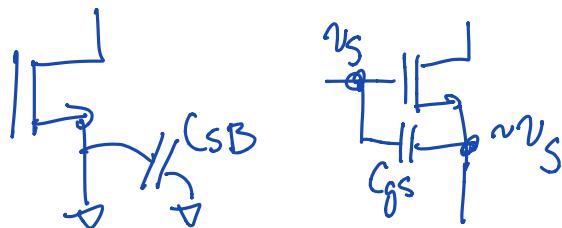
$$C_{in} = C_{gd} + \left(1 - \frac{g_m (r_o \parallel r_{oc})}{1 + g_m (r_o \parallel r_{oc})}\right) C_{gs}$$

$$C_{in} = C_{gd} + \left(\frac{1}{1 + g_m (r_o \parallel r_{oc})}\right) C_{gs}$$

$$C_{in} \approx C_{gd}$$

(for large $g_m (r_o \parallel r_{oc})$)

heavily attenuated

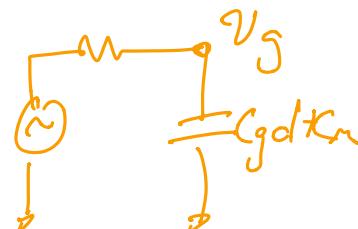


Bandwidth of Source Follower

Input low-pass filter's -3 dB frequency:

$$\omega_p^{-1} = R_S \left(C_{gd} + \frac{C_{gs}}{1 + g_m(r_o \| r_{oc})} \right)$$

Small



Substitute favorable values of R_S , r_o :

$$\underline{R_S \approx 1/g_m} \quad \underline{r_o \gg 1/g_m}$$

$$\omega_p^{-1} \approx (1/g_m) \left(C_{gd} + \frac{C_{gs}}{1 + BIG} \right) \approx \underline{\underline{C_{gd}/g_m}}$$

Very high frequency!
Model not valid at
these high frequencies

$$\underline{\underline{\omega_p \approx g_m / C_{gd}}}$$

Some Examples

Common source amplifier:

A_{vCgd} = Negative, large number (-100)

$$\underline{C}_{Miller} = (1 - \underline{A}_{V,C_{gd}}) C_{gd} \approx \underline{100} C_{gd}$$

Miller Multiplied Cap has detrimental impact on bandwidth

Common drain amplifier: *source follower*

A_{vCgs} = Slightly less than 1 *& positive*

$$\underline{C}_{Miller} = (1 - \underline{A}_{V,C_{gs}}) C_{gs} \approx \underline{0}$$

“Bootstrapped” cap has negligible impact on bandwidth!



